

In re Appln. of MORIWAKI et al.
Application No. Unassigned

ABSTRACT AMENDMENTS

Replace the Abstract with:

~~A high-frequency~~ An integrated circuit device includes a semiconductor amplification element and a bias circuit for applying a bias voltage to the semiconductor amplification element. A power source of the bias circuit is connected to a power source of the semiconductor amplification element via a semiconductor element such that idle current of the semiconductor amplification element ~~can be~~ is changed in response to a change of a supply voltage of the semiconductor amplification element.